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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	276480
Number of I/O	280
Number of Gates	1500000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m1a3pe1500-1fgg484i

Temperature Grade Offerings

Package	A3PE600	A3PE1500	A3PE3000
Cortex-M1 Devices		M1A3PE1500	M1A3PE3000
PQ208	C, I	C, I	C, I
FG256	C, I	–	–
FG324	–	–	C, I
FG484	C, I	C, I	C, I
FG676	–	C, I	–
FG896	–	–	C, I

Note: C = Commercial temperature range: 0°C to 70°C ambient temperature

I = Industrial temperature range: -40°C to 85°C ambient temperature

Speed Grade and Temperature Grade Matrix

Temperature Grade	Std.	-1	-2
C ¹	✓	✓	✓
I ²	✓	✓	✓

Notes:

1. C = Commercial temperature range: 0°C to 70°C ambient temperature

2. I = Industrial temperature range: -40°C to 85°C ambient temperature

References made to ProASIC3E devices also apply to ARM-enabled ProASIC3E devices. The ARM-enabled part numbers start with M1 (Cortex-M1).

Contact your local Microsemi SoC Products Group representative for device availability:

www.microsemi.com/index.php?option=com_content&id=135&lang=en&view=article.

User I/O Characteristics

Timing Model

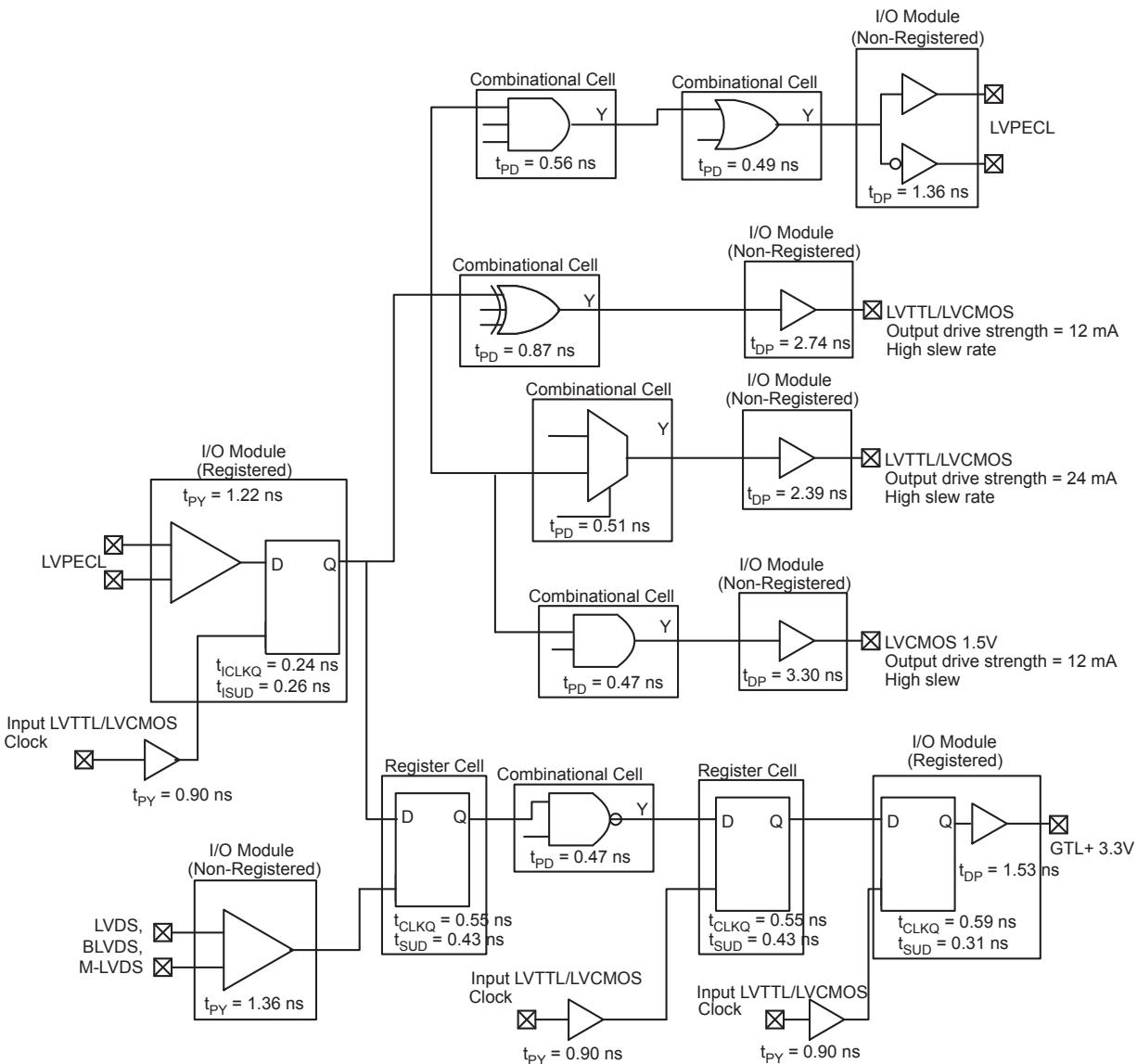


Figure 2-2 • Timing Model

**Operating Conditions: –2 Speed, Commercial Temperature Range ($T_J = 70^\circ\text{C}$), Worst-Case
VCC = 1.425 V**

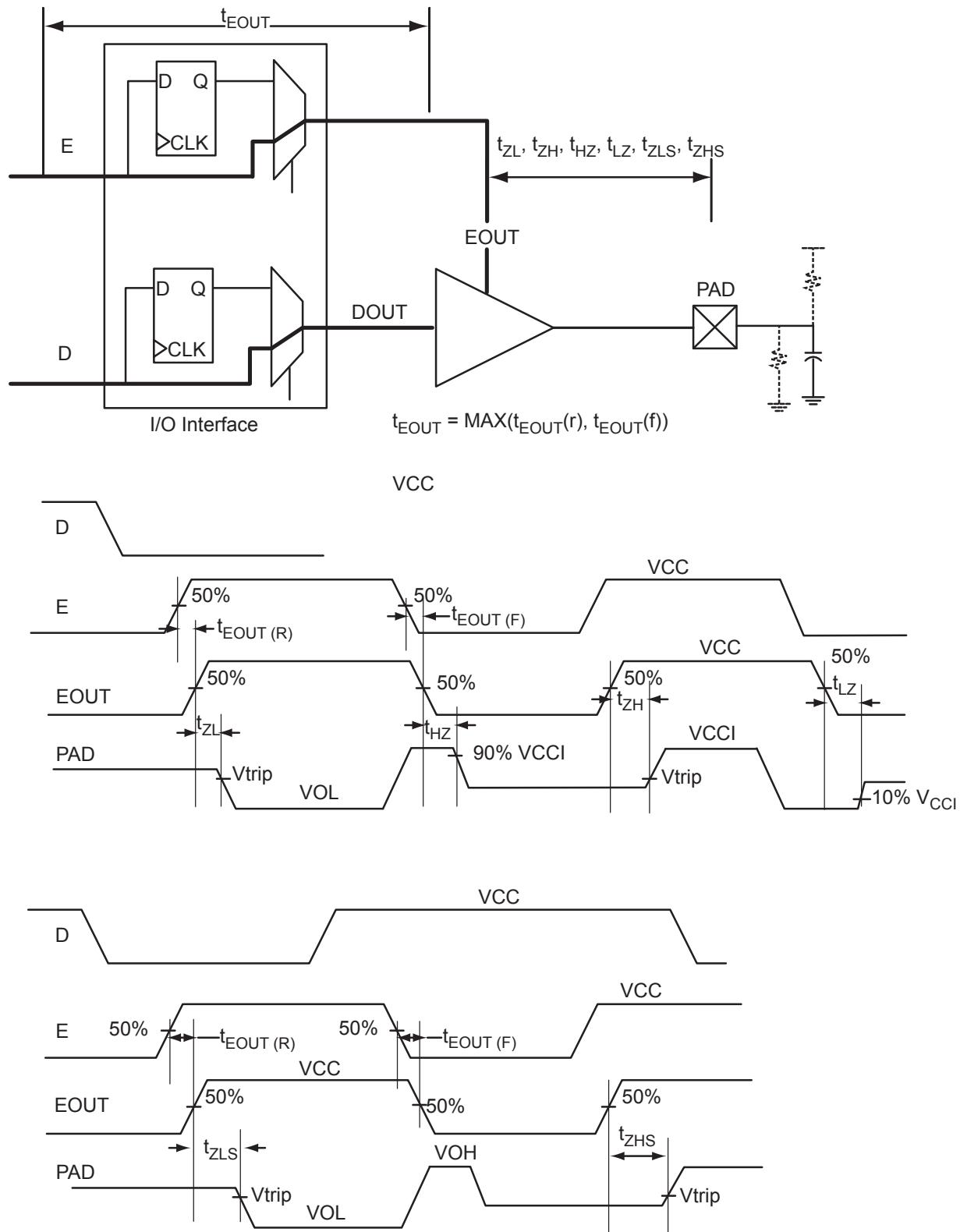


Figure 2-5 • Tristate Output Buffer Timing Model and Delays (example)

Table 2-22 • Duration of Short Circuit Event Before Failure (continued)

Temperature	Time before Failure
85°C	2 years
100°C	6 months

Table 2-23 • Schmitt Trigger Input Hysteresis
Hysteresis Voltage Value (typ.) for Schmitt Mode Input Buffers

Input Buffer Configuration	Hysteresis Value (typ.)
3.3 V LVTTL/LVC MOS/PCI/PCI-X (Schmitt trigger mode)	240 mV
2.5 V LVC MOS (Schmitt trigger mode)	140 mV
1.8 V LVC MOS (Schmitt trigger mode)	80 mV
1.5 V LVC MOS (Schmitt trigger mode)	60 mV

Table 2-24 • I/O Input Rise Time, Fall Time, and Related I/O Reliability*

Input Buffer	Input Rise/Fall Time (min.)	Input Rise/Fall Time (max.)	Reliability
LV TTL/LVC MOS (Schmitt trigger disabled)	No requirement	10 ns *	20 years (110°C)
LV TTL/LVC MOS (Schmitt trigger enabled)	No requirement	No requirement, but input noise voltage cannot exceed Schmitt hysteresis.	20 years (110°C)
HSTL/SSTL/GTL	No requirement	10 ns *	10 years (100°C)
LVDS/B-LVDS/M-LVDS/ LVPECL	No requirement	10 ns *	10 years (100°C)

Note: *For clock signals and similar edge-generating signals, refer to the "ProASIC3/E SSO and Pin Placement Guidelines" chapter of the [ProASIC3E FPGA Fabric User's Guide](#). The maximum input rise/fall time is related to the noise induced into the input buffer trace. If the noise is low, then the rise time and fall time of input buffers can be increased beyond the maximum value. The longer the rise/fall times, the more susceptible the input signal is to the board noise. Microsemi recommends signal integrity evaluation/characterization of the system to ensure that there is no excessive noise coupling into input signals.

3.3 V LVC MOS Wide Range

Table 2-29 • Minimum and Maximum DC Input and Output Levels

3.3 V LVC MOS Wide Range	Equivalent Software Default Drive	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL ²	IIH ³
Drive Strength	Strength Option ¹	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	μA	μA	Max. mA ⁴	Max. mA ⁴	μA ⁵	μA ⁵
100 μA	2 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	27	25	10	10
100 μA	4 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	27	25	10	10
100 μA	6 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	54	51	10	10
100 μA	8 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	54	51	10	10
100 μA	12 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	109	103	10	10
100 μA	16 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	127	132	10	10
100 μA	24 mA	-0.3	0.8	2	3.6	0.2	VDD - 0.2	100	100	181	268	10	10

Notes:

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is $\pm 100 \mu\text{A}$. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. IIL is the input leakage current per I/O pin over recommended operation conditions where $-0.3 \text{ V} < \text{VIN} < \text{VIL}$.
3. IIH is the input leakage current per I/O pin over recommended operating conditions $\text{VIH} < \text{VIN} < \text{VCCI}$. Input current is larger when operating outside recommended ranges.
4. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
5. Currents are measured at 85°C junction temperature.
6. Software default selection highlighted in gray.

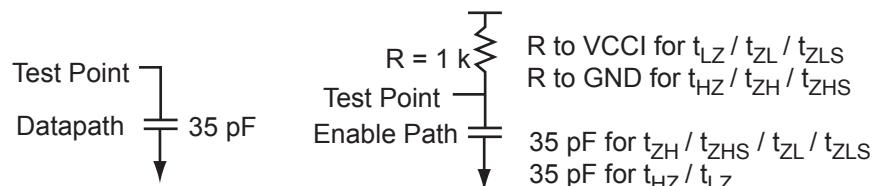


Figure 2-7 • AC Loading

Table 2-30 • 3.3 V LVC MOS Wide Range AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C _{LOAD} (pF)
0	3.3	1.4	-	35

Note: *Measuring point = Vtrip. See Table 2-15 on page 2-18 for a complete table of trip points.

Table 2-32 • 3.3 V LVC MOS Wide Range Low SlewCommercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option ¹	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
100 μA	4 mA	Std.	0.66	17.02	0.04	1.83	2.38	0.43	17.02	13.74	4.16	3.78	20.42	17.14	ns
		-1	0.56	14.48	0.04	1.55	2.02	0.36	14.48	11.69	3.54	3.21	17.37	14.58	ns
		-2	0.49	12.71	0.03	1.36	1.78	0.32	12.71	10.26	3.11	2.82	15.25	12.80	ns
100 μA	8 mA	Std.	0.66	12.16	0.04	1.83	2.38	0.43	12.16	9.78	4.70	4.74	15.55	13.17	ns
		-1	0.56	10.34	0.04	1.55	2.02	0.36	10.34	8.32	4.00	4.03	13.23	11.20	ns
		-2	0.49	9.08	0.03	1.36	1.78	0.32	9.08	7.30	3.51	3.54	11.61	9.84	ns
100 μA	12 mA	Std.	0.66	9.32	0.04	1.83	2.38	0.43	9.32	7.62	5.06	5.36	12.71	11.02	ns
		-1	0.56	7.93	0.04	1.55	2.02	0.36	7.93	6.48	4.31	4.56	10.81	9.37	ns
		-2	0.49	6.96	0.03	1.36	1.78	0.32	6.96	5.69	3.78	4.00	9.49	8.23	ns
100 μA	16 mA	Std.	0.66	8.69	0.04	1.83	2.38	0.43	8.69	7.17	5.14	5.53	12.08	10.57	ns
		-1	0.56	7.39	0.04	1.55	2.02	0.36	7.39	6.10	4.37	4.71	10.28	8.99	ns
		-2	0.49	6.49	0.03	1.36	1.78	0.32	6.49	5.36	3.83	4.13	9.02	7.89	ns
100 μA	24 mA	Std.	0.66	8.11	0.04	1.83	2.38	0.43	8.11	7.13	5.23	6.13	11.50	10.52	ns
		-1	0.56	6.90	0.04	1.55	2.02	0.36	6.90	6.06	4.45	5.21	9.78	8.95	ns
		-2	0.49	6.05	0.03	1.36	1.78	0.32	6.05	5.32	3.91	4.57	8.59	7.86	ns

Notes:

1. The minimum drive strength for any LVC MOS 3.3 V software configuration when run in wide range is $\pm 100 \mu\text{A}$. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
2. Software default selection highlighted in gray.
3. For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

1.8 V LVCMOS

Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

Table 2-37 • Minimum and Maximum DC Input and Output Levels

1.8 V LVCMOS	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ³	Max. mA ³	µA ⁴	µA ⁴
2 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	2	2	11	9	10	10
4 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	4	4	22	17	10	10
6 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	6	6	44	35	10	10
8 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	8	8	51	45	10	10
12 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	12	12	74	91	10	10
16 mA	-0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI - 0.45	16	16	74	91	10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where $-0.3 \text{ V} < \text{VIN} < \text{VIL}$.
2. IIH is the input leakage current per I/O pin over recommended operating conditions $\text{VIH} < \text{VIN} < \text{VCCI}$. Input current is larger when operating outside recommended ranges.
3. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
4. Currents are measured at 85°C junction temperature.
5. Software default selection highlighted in gray.

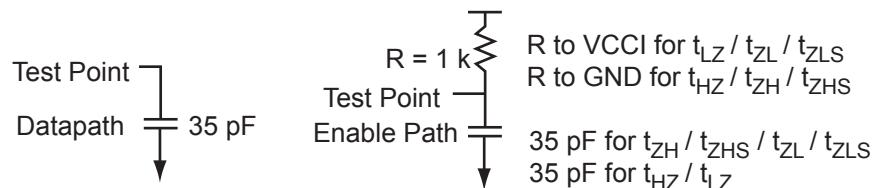


Figure 2-9 • AC Loading

Table 2-38 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C _{LOAD} (pF)
0	1.8	0.9	-	35

Note: *Measuring point = V_{trip} . See [Table 2-15](#) on page 2-18 for a complete table of trip points.

3.3 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-54 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL+	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL	IIH
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA ¹	Max. mA ¹	µA ²	µA ²
35 mA	-0.3	VREF - 0.1	VREF + 0.1	3.6	0.6	-	35	35	181	268	10	10

Notes:

1. Currents are measured at high temperature (100°C junction temperature) and maximum voltage.
2. Currents are measured at 85°C junction temperature.

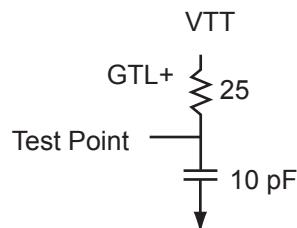


Figure 2-14 • AC Loading

Table 2-55 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C _{LOAD} (pF)
VREF - 0.1	VREF + 0.1	1.0	1.0	1.5	10

Note: *Measuring point = Vtrip. See [Table 2-15 on page 2-18](#) for a complete table of trip points.

Timing Characteristics

Table 2-56 • 3.3 V GTL+

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V,
Worst-Case VCCI = 3.0 V, VREF = 1.0 V

Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{EOUT}	t _{ZL}	t _{ZH}	t _{LZ}	t _{HZ}	t _{ZLS}	t _{ZHS}	Units
Std.	0.60	2.06	0.04	1.59	0.43	2.09	2.06			4.33	4.29	ns
-1	0.51	1.75	0.04	1.35	0.36	1.78	1.75			3.68	3.65	ns
-2	0.45	1.53	0.03	1.19	0.32	1.56	1.53			3.23	3.20	ns

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-6 on page 2-5](#) for derating values.

Timing Characteristics

Table 2-93 • Combinatorial Cell Propagation Delays
 Commercial-Case Conditions: $T_J = 70^\circ\text{C}$, Worst-Case VCC = 1.425 V

Combinatorial Cell	Equation	Parameter	-2	-1	Std.	Units
INV	$Y = !A$	t_{PD}	0.40	0.46	0.54	ns
AND2	$Y = A \cdot B$	t_{PD}	0.47	0.54	0.63	ns
NAND2	$Y = !(A \cdot B)$	t_{PD}	0.47	0.54	0.63	ns
OR2	$Y = A + B$	t_{PD}	0.49	0.55	0.65	ns
NOR2	$Y = !(A + B)$	t_{PD}	0.49	0.55	0.65	ns
XOR2	$Y = A \oplus B$	t_{PD}	0.74	0.84	0.99	ns
MAJ3	$Y = MAJ(A, B, C)$	t_{PD}	0.70	0.79	0.93	ns
XOR3	$Y = A \oplus B \oplus C$	t_{PD}	0.87	1.00	1.17	ns
MUX2	$Y = A IS + B S$	t_{PD}	0.51	0.58	0.68	ns
AND3	$Y = A \cdot B \cdot C$	t_{PD}	0.56	0.64	0.75	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

VersaTile Specifications as a Sequential Module

The ProASIC3E library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library. For more details, refer to the [Fusion, IGLOO/e, and ProASIC3/E Macro Library Guide](#).

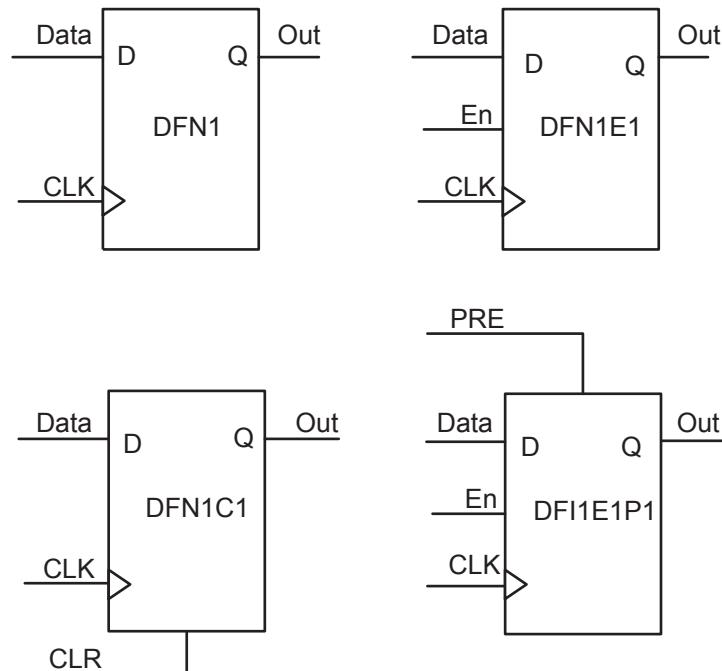


Figure 2-36 • Sample of Sequential Cells

Embedded SRAM and FIFO Characteristics

SRAM

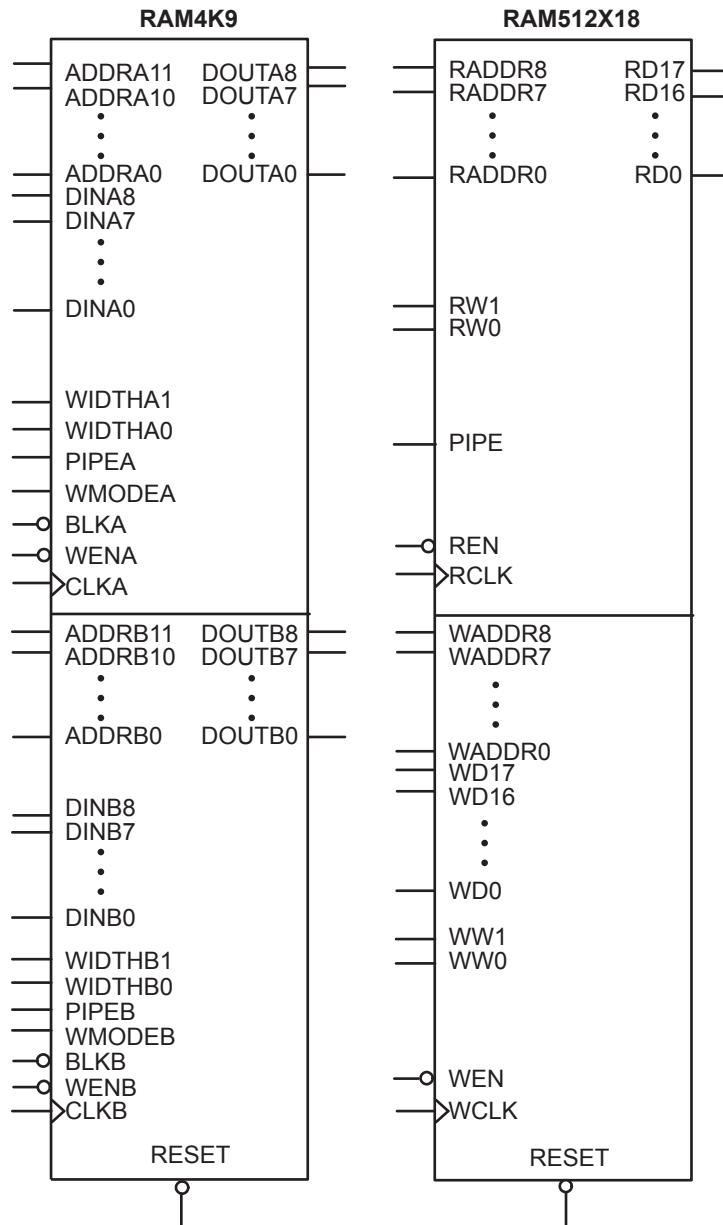


Figure 2-40 • RAM Models

Timing Waveforms

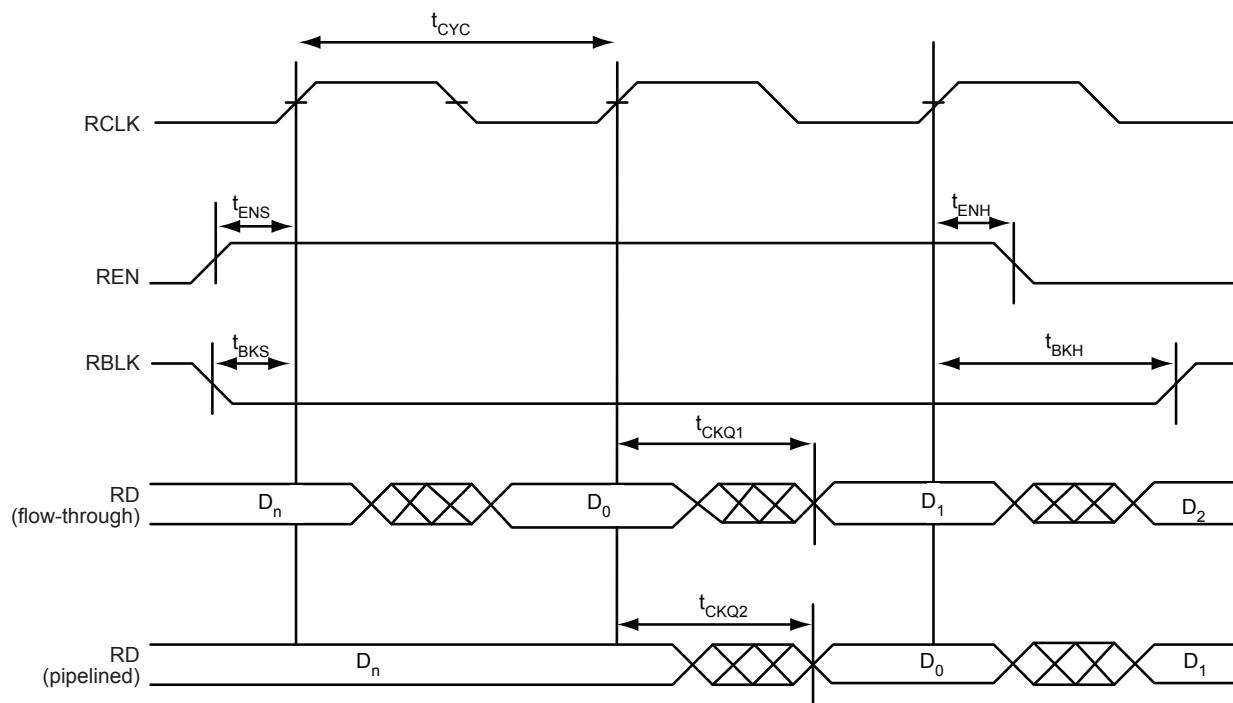


Figure 2-47 • FIFO Read

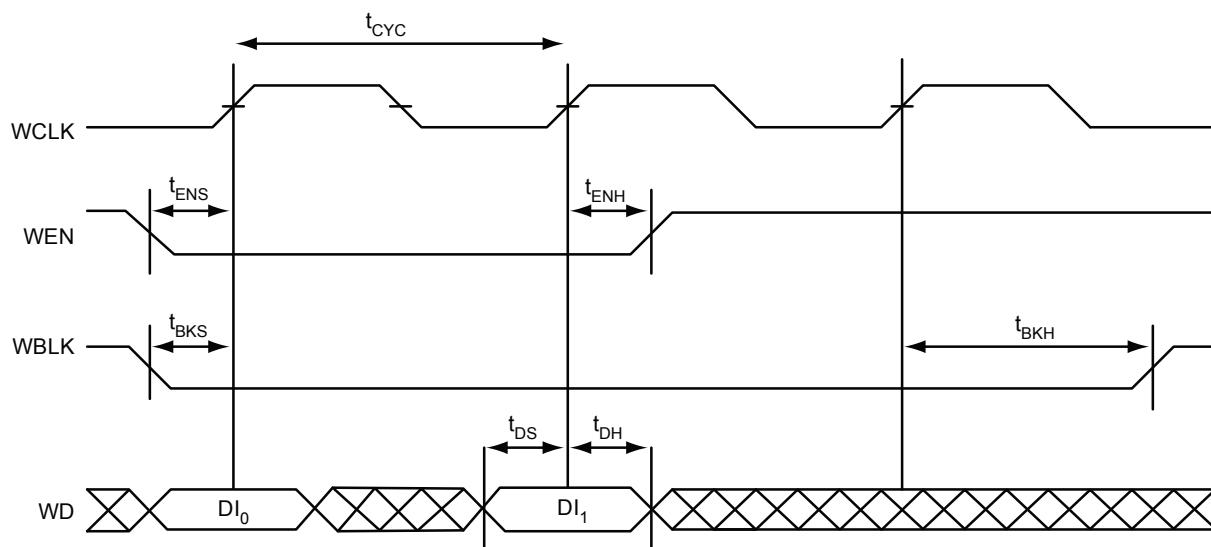


Figure 2-48 • FIFO Write

PQ208	
Pin Number	A3PE600 Function
1	GND
2	GNDQ
3	VMV7
4	GAB2/IO133PSB7V1
5	GAA2/IO134PDB7V1
6	IO134NDB7V1
7	GAC2/IO132PDB7V1
8	IO132NDB7V1
9	IO130PDB7V1
10	IO130NDB7V1
11	IO127PDB7V1
12	IO127NDB7V1
13	IO126PDB7V0
14	IO126NDB7V0
15	IO124PSB7V0
16	VCC
17	GND
18	VCCIB7
19	IO122PPB7V0
20	IO121PSB7V0
21	IO122NPB7V0
22	GFC1/IO120PSB7V0
23	GFB1/IO119PDB7V0
24	GFB0/IO119NDB7V0
25	VCOMPLF
26	GFA0/IO118NPB6V1
27	VCCPLF
28	GFA1/IO118PPB6V1
29	GND
30	GFA2/IO117PDB6V1
31	IO117NDB6V1
32	GFB2/IO116PPB6V1
33	GFC2/IO115PPB6V1
34	IO116NPB6V1
35	IO115NPB6V1
36	VCC

PQ208	
Pin Number	A3PE600 Function
37	IO112PDB6V1
38	IO112NDB6V1
39	IO108PSB6V0
40	VCCIB6
41	GND
42	IO106PDB6V0
43	IO106NDB6V0
44	GEC1/IO104PDB6V0
45	GEC0/IO104NDB6V0
46	GEB1/IO103PPB6V0
47	GEA1/IO102PPB6V0
48	GEB0/IO103NPB6V0
49	GEA0/IO102NPB6V0
50	VMV6
51	GNDQ
52	GND
53	VMV5
54	GNDQ
55	IO101NDB5V2
56	GEA2/IO101PDB5V2
57	IO100NDB5V2
58	GEB2/IO100PDB5V2
59	IO99NDB5V2
60	GEC2/IO99PDB5V2
61	IO98PSB5V2
62	VCCIB5
63	IO96PSB5V2
64	IO94NDB5V1
65	GND
66	IO94PDB5V1
67	IO92NDB5V1
68	IO92PDB5V1
69	IO88NDB5V0
70	IO88PDB5V0
71	VCC

PQ208	
Pin Number	A3PE600 Function
72	VCCIB5
73	IO85NPB5V0
74	IO84NPB5V0
75	IO85PPB5V0
76	IO84PPB5V0
77	IO83NPB5V0
78	IO82NPB5V0
79	IO83PPB5V0
80	IO82PPB5V0
81	GND
82	IO80NDB4V1
83	IO80PDB4V1
84	IO79NPB4V1
85	IO78NPB4V1
86	IO79PPB4V1
87	IO78PPB4V1
88	VCC
89	VCCIB4
90	IO76NDB4V1
91	IO76PDB4V1
92	IO72NDB4V0
93	IO72PDB4V0
94	IO70NDB4V0
95	GDC2/IO70PDB4V0
96	IO68NDB4V0
97	GND
98	GDA2/IO68PDB4V0
99	GDB2/IO69PSB4V0
100	GNDQ
101	TCK
102	TDI
103	TMS
104	VMV4
105	GND
106	VPUMP
107	GNDQ

FG484	
Pin Number	A3PE600 Function
A1	GND
A2	GND
A3	VCCIB0
A4	IO06NDB0V1
A5	IO06PDB0V1
A6	IO08NDB0V1
A7	IO08PDB0V1
A8	IO11PDB0V1
A9	IO17PDB0V2
A10	IO18NDB0V2
A11	IO18PDB0V2
A12	IO22PDB1V0
A13	IO26PDB1V0
A14	IO29NDB1V1
A15	IO29PDB1V1
A16	IO31NDB1V1
A17	IO31PDB1V1
A18	IO32NDB1V1
A19	NC
A20	VCCIB1
A21	GND
A22	GND
AA1	GND
AA2	VCCIB6
AA3	NC
AA4	IO98PDB5V2
AA5	IO96NDB5V2
AA6	IO96PDB5V2
AA7	IO86NDB5V0
AA8	IO86PDB5V0
AA9	IO85PDB5V0
AA10	IO85NDB5V0
AA11	IO78PPB4V1
AA12	IO79NDB4V1
AA13	IO79PDB4V1
AA14	NC

FG484	
Pin Number	A3PE600 Function
AA15	NC
AA16	IO71NDB4V0
AA17	IO71PDB4V0
AA18	NC
AA19	NC
AA20	NC
AA21	VCCIB3
AA22	GND
AB1	GND
AB2	GND
AB3	VCCIB5
AB4	IO97NDB5V2
AB5	IO97PDB5V2
AB6	IO93NDB5V1
AB7	IO93PDB5V1
AB8	IO87NDB5V0
AB9	IO87PDB5V0
AB10	NC
AB11	NC
AB12	IO75NDB4V1
AB13	IO75PDB4V1
AB14	IO72NDB4V0
AB15	IO72PDB4V0
AB16	IO73NDB4V0
AB17	IO73PDB4V0
AB18	NC
AB19	NC
AB20	VCCIB4
AB21	GND
AB22	GND
B1	GND
B2	VCCIB7
B3	NC
B4	IO03NDB0V0
B5	IO03PDB0V0
B6	IO07NDB0V1

FG484	
Pin Number	A3PE600 Function
B7	IO07PDB0V1
B8	IO11NDB0V1
B9	IO17NDB0V2
B10	IO14PDB0V2
B11	IO19PDB0V2
B12	IO22NDB1V0
B13	IO26NDB1V0
B14	NC
B15	NC
B16	IO30NDB1V1
B17	IO30PDB1V1
B18	IO32PDB1V1
B19	NC
B20	NC
B21	VCCIB2
B22	GND
C1	VCCIB7
C2	NC
C3	NC
C4	NC
C5	GND
C6	IO04NDB0V0
C7	IO04PDB0V0
C8	VCC
C9	VCC
C10	IO14NDB0V2
C11	IO19NDB0V2
C12	NC
C13	NC
C14	VCC
C15	VCC
C16	NC
C17	NC
C18	GND
C19	NC
C20	NC

FG484	
Pin Number	A3PE1500 Function
V15	IO112NDB4V0
V16	GDB2/IO112PDB4V0
V17	TDI
V18	GNDQ
V19	TDO
V20	GND
V21	NC
V22	IO105NDB3V2
W1	NC
W2	NC
W3	NC
W4	GND
W5	IO165NDB5V3
W6	GEB2/IO165PDB5V3
W7	IO164NDB5V3
W8	IO153NDB5V2
W9	IO153PDB5V2
W10	IO147NDB5V1
W11	IO133NDB4V2
W12	IO130NDB4V2
W13	IO130PDB4V2
W14	IO113NDB4V0
W15	GDC2/IO113PDB4V0
W16	IO111NDB4V0
W17	GDA2/IO111PDB4V0
W18	TMS
W19	GND
W20	NC
W21	NC
W22	NC
Y1	VCCIB6
Y2	NC
Y3	NC
Y4	IO161NDB5V3
Y5	GND
Y6	IO163NDB5V3

FG484	
Pin Number	A3PE1500 Function
Y7	IO163PDB5V3
Y8	VCC
Y9	VCC
Y10	IO147PDB5V1
Y11	IO133PDB4V2
Y12	IO131NPB4V2
Y13	NC
Y14	VCC
Y15	VCC
Y16	NC
Y17	NC
Y18	GND
Y19	NC
Y20	NC
Y21	NC
Y22	VCCIB3

FG484	
Pin Number	A3PE3000 Function
A1	GND
A2	GND
A3	VCCIB0
A4	IO10NDB0V1
A5	IO10PDB0V1
A6	IO16NDB0V1
A7	IO16PDB0V1
A8	IO18PDB0V2
A9	IO24PDB0V2
A10	IO28NDB0V3
A11	IO28PDB0V3
A12	IO46PDB1V0
A13	IO54PDB1V1
A14	IO56NDB1V1
A15	IO56PDB1V1
A16	IO64NDB1V2
A17	IO64PDB1V2
A18	IO72NDB1V3
A19	IO74NDB1V4
A20	VCCIB1
A21	GND
A22	GND
AA1	GND
AA2	VCCIB6
AA3	IO228PDB5V4
AA4	IO224PDB5V3
AA5	IO218NDB5V3
AA6	IO218PDB5V3
AA7	IO212NDB5V2
AA8	IO212PDB5V2
AA9	IO198PDB5V0
AA10	IO198NDB5V0
AA11	IO188PPB4V4
AA12	IO180NDB4V3
AA13	IO180PDB4V3
AA14	IO170NDB4V2

FG484	
Pin Number	A3PE3000 Function
AA15	IO170PDB4V2
AA16	IO166NDB4V1
AA17	IO166PDB4V1
AA18	IO160NDB4V0
AA19	IO160PDB4V0
AA20	IO158NPB4V0
AA21	VCCIB3
AA22	GND
AB1	GND
AB2	GND
AB3	VCCIB5
AB4	IO216NDB5V2
AB5	IO216PDB5V2
AB6	IO210NDB5V2
AB7	IO210PDB5V2
AB8	IO208NDB5V1
AB9	IO208PDB5V1
AB10	IO197NDB5V0
AB11	IO197PDB5V0
AB12	IO174NDB4V2
AB13	IO174PDB4V2
AB14	IO172NDB4V2
AB15	IO172PDB4V2
AB16	IO168NDB4V1
AB17	IO168PDB4V1
AB18	IO162NDB4V1
AB19	IO162PDB4V1
AB20	VCCIB4
AB21	GND
AB22	GND
B1	GND
B2	VCCIB7
B3	IO06PPB0V0
B4	IO08NDB0V0
B5	IO08PDB0V0
B6	IO14NDB0V1

FG484	
Pin Number	A3PE3000 Function
B7	IO14PDB0V1
B8	IO18NDB0V2
B9	IO24NDB0V2
B10	IO34PDB0V4
B11	IO40PDB0V4
B12	IO46NDB1V0
B13	IO54NDB1V1
B14	IO62NDB1V2
B15	IO62PDB1V2
B16	IO68NDB1V3
B17	IO68PDB1V3
B18	IO72PDB1V3
B19	IO74PDB1V4
B20	IO76NPB1V4
B21	VCCIB2
B22	GND
C1	VCCIB7
C2	IO303PDB7V3
C3	IO305PDB7V3
C4	IO06NPB0V0
C5	GND
C6	IO12NDB0V1
C7	IO12PDB0V1
C8	VCC
C9	VCC
C10	IO34NDB0V4
C11	IO40NDB0V4
C12	IO48NDB1V0
C13	IO48PDB1V0
C14	VCC
C15	VCC
C16	IO70NDB1V3
C17	IO70PDB1V3
C18	GND
C19	IO76PPB1V4
C20	IO88NDB2V0

FG484		FG484		FG484	
Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function	Pin Number	A3PE3000 Function
H19	IO100PDB2V2	K11	GND	M3	IO272NDB6V4
H20	VCC	K12	GND	M4	GFA2/IO272PDB6V4
H21	VMV2	K13	GND	M5	GFA1/IO273PDB6V4
H22	IO105PDB2V2	K14	VCC	M6	VCCPLF
J1	IO285NDB7V1	K15	VCCIB2	M7	IO271NDB6V4
J2	IO285PDB7V1	K16	GCC1/IO112PPB2V3	M8	GFB2/IO271PDB6V4
J3	VMV7	K17	IO108NDB2V3	M9	VCC
J4	IO279PDB7V0	K18	IO108PDB2V3	M10	GND
J5	IO283PDB7V1	K19	IO110NPB2V3	M11	GND
J6	IO281PDB7V0	K20	IO106NPB2V3	M12	GND
J7	IO287NDB7V1	K21	IO109NDB2V3	M13	GND
J8	VCCIB7	K22	IO107NDB2V3	M14	VCC
J9	GND	L1	IO257PSB6V2	M15	GCB2/IO116PPB3V0
J10	VCC	L2	IO276PDB7V0	M16	GCA1/IO114PPB3V0
J11	VCC	L3	IO276NDB7V0	M17	GCC2/IO117PPB3V0
J12	VCC	L4	GFB0/IO274NPB7V0	M18	VCCPLC
J13	VCC	L5	GFA0/IO273NDB6V4	M19	GCA2/IO115PDB3V0
J14	GND	L6	GFB1/IO274PPB7V0	M20	IO115NDB3V0
J15	VCCIB2	L7	VCOMPLF	M21	IO126PDB3V1
J16	IO84NDB2V0	L8	GFC0/IO275NPB7V0	M22	IO124PSB3V1
J17	IO104NDB2V2	L9	VCC	N1	IO255PPB6V2
J18	IO104PDB2V2	L10	GND	N2	IO253NDB6V2
J19	IO106PPB2V3	L11	GND	N3	VMV6
J20	GNDQ	L12	GND	N4	GFC2/IO270PPB6V4
J21	IO109PDB2V3	L13	GND	N5	IO261PPB6V3
J22	IO107PDB2V3	L14	VCC	N6	IO263PDB6V3
K1	IO277NDB7V0	L15	GCC0/IO112NPB2V3	N7	IO263NDB6V3
K2	IO277PDB7V0	L16	GCB1/IO113PPB2V3	N8	VCCIB6
K3	GNDQ	L17	GCA0/IO114NPB3V0	N9	VCC
K4	IO279NDB7V0	L18	VCOMPLC	N10	GND
K5	IO283NDB7V1	L19	GCB0/IO113NPB2V3	N11	GND
K6	IO281NDB7V0	L20	IO110PPB2V3	N12	GND
K7	GFC1/IO275PPB7V0	L21	IO111NDB2V3	N13	GND
K8	VCCIB7	L22	IO111PDB2V3	N14	VCC
K9	VCC	M1	GNDQ	N15	VCCIB3
K10	GND	M2	IO255NPB6V2	N16	IO116NPB3V0

FG484	
Pin Number	A3PE3000 Function
N17	IO132NPB3V2
N18	IO117NPB3V0
N19	IO132PPB3V2
N20	GNDQ
N21	IO126NDB3V1
N22	IO128PDB3V1
P1	IO247PDB6V1
P2	IO253PDB6V2
P3	IO270NPB6V4
P4	IO261NPB6V3
P5	IO249PPB6V1
P6	IO259PDB6V3
P7	IO259NDB6V3
P8	VCCIB6
P9	GND
P10	VCC
P11	VCC
P12	VCC
P13	VCC
P14	GND
P15	VCCIB3
P16	GDB0/IO152NPB3V4
P17	IO136NDB3V2
P18	IO136PDB3V2
P19	IO138PDB3V3
P20	VMV3
P21	IO130PDB3V2
P22	IO128NDB3V1
R1	IO247NDB6V1
R2	IO245PDB6V1
R3	VCC
R4	IO249NPB6V1
R5	IO251NDB6V2
R6	IO251PDB6V2
R7	GEC0/IO236NPB6V0
R8	VMV5

FG484	
Pin Number	A3PE3000 Function
R9	VCCIB5
R10	VCCIB5
R11	IO196NDB5V0
R12	IO196PDB5V0
R13	VCCIB4
R14	VCCIB4
R15	VMV3
R16	VCCPLD
R17	GDB1/IO152PPB3V4
R18	GDC1/IO151PDB3V4
R19	IO138NDB3V3
R20	VCC
R21	IO130NDB3V2
R22	IO134PDB3V2
T1	IO243PPB6V1
T2	IO245NDB6V1
T3	IO243NPB6V1
T4	IO241PDB6V0
T5	IO241NDB6V0
T6	GEC1/IO236PPB6V0
T7	VCOMPLE
T8	GNDQ
T9	GEA2/IO233PPB5V4
T10	IO206NDB5V1
T11	IO202NDB5V1
T12	IO194NDB5V0
T13	IO186NDB4V4
T14	IO186PDB4V4
T15	GNDQ
T16	VCOMPLD
T17	VJTAG
T18	GDC0/IO151NDB3V4
T19	GDA1/IO153PDB3V4
T20	IO144PDB3V3
T21	IO140PDB3V3
T22	IO134NDB3V2

FG484	
Pin Number	A3PE3000 Function
U1	IO240PPB6V0
U2	IO238PDB6V0
U3	IO238NDB6V0
U4	GEB1/IO235PDB6V0
U5	GEB0/IO235NDB6V0
U6	VMV6
U7	VCCPLE
U8	IO233NPB5V4
U9	IO222PPB5V3
U10	IO206PDB5V1
U11	IO202PDB5V1
U12	IO194PDB5V0
U13	IO176NDB4V2
U14	IO176PDB4V2
U15	VMV4
U16	TCK
U17	VPUMP
U18	TRST
U19	GDA0/IO153NDB3V4
U20	IO144NDB3V3
U21	IO140NDB3V3
U22	IO142PDB3V3
V1	IO239PDB6V0
V2	IO240NPB6V0
V3	GND
V4	GEA1/IO234PDB6V0
V5	GEA0/IO234NDB6V0
V6	GNDQ
V7	GEC2/IO231PDB5V4
V8	IO222NPB5V3
V9	IO204NDB5V1
V10	IO204PDB5V1
V11	IO195NDB5V0
V12	IO195PDB5V0
V13	IO178NDB4V3
V14	IO178PDB4V3

Revision	Changes	Page
Revision 11 (August 2012)	<p>Added a Note stating "VMV pins must be connected to the corresponding VCCI pins. See the "VMVx I/O Supply Voltage (quiet)" section on page 3-1 for further information." to Table 2-1 • Absolute Maximum Ratings and Table 2-2 • Recommended Operating Conditions¹ (SAR 38322).</p> <p>The drive strength, IOL, and IOH value for 3.3 V GTL and 2.5 V GTL was changed from 25 mA to 20 mA in the following tables (SAR 31924):</p> <ul style="list-style-type: none"> "Summary of Maximum and Minimum DC Input and Output Levels" table "Summary of I/O Timing Characteristics—Software Default Settings" table "I/O Output Buffer Maximum Resistances¹" table "Minimum and Maximum DC Input and Output Levels" table "Minimum and Maximum DC Input and Output Levels" table <p>Also added note stating "Output drive strength is below JEDEC specification" for Tables 2-17 and 2-19.</p> <p>Additionally, the IOL and IOH values for 3.3 V GTL+ and 2.5 V GTL+ were corrected from 51 to 35 (for 3.3 V GTL+) and from 40 to 33 (for 2.5 V GTL+) in table Table 2-13 (SAR 39714).</p> <p>"Duration of Short Circuit Event Before Failure" table was revised to change the maximum temperature from 110°C to 100°C, with an example of six months instead of three months (SAR 37934).</p> <p>The following sentence was deleted from the "2.5 V LVCMOS" section (SAR 34796):</p> <p>"It uses a 5 V-tolerant input buffer and push-pull output buffer." This change was made in revision 10 and omitted from the change table in error.</p>	2-1 3-1 2-1 2-16 2-19 2-20 2-39 2-40 2-22 2-30
Revision 11 (continued)	Figure 2-11 was updated to match tables in the " Summary of I/O Timing Characteristics – Default I/O Software Settings " section (SAR 34889).	2-38
	In Table 2-81 VIL and VIH were revised so that the maximum is 3.6 V for all listed values of VCCI (SAR 37222).	2-52
	Figure 2-47 and Figure 2-48 are new (SAR 34848).	2-79
	The following sentence was removed from the " VMVx I/O Supply Voltage (quiet) " section in the " Pin Descriptions and Packaging " chapter: "Within the package, the VMV plane is decoupled from the simultaneous switching noise originating from the output buffer VCCI domain" and replaced with "Within the package, the VMV plane biases the input stage of the I/Os in the I/O banks" (SAR 38322). The datasheet mentions that "VMV pins must be connected to the corresponding VCCI pins" for an ESD enhancement.	3-1

Revision	Changes	Page
v2.0 (continued)	Table 3-6 • Temperature and Voltage Derating Factors for Timing Delays was updated.	3-5
	Table 3-5 • Package Thermal Resistivities was updated.	3-5
	Table 3-10 • Different Components Contributing to the Dynamic Power Consumption in ProASIC3E Devices was updated.	3-8
	t_{WRO} and t_{CCKH} were added to Table 3-94 • RAM4K9 and Table 3-95 • RAM512X18.	3-74 to 3-74
	The note in Table 3-24 • I/O Input Rise Time, Fall Time, and Related I/O Reliability was updated.	3-23
	Figure 3-43 • Write Access After Write onto Same Address, Figure 3-44 • Read Access After Write onto Same Address, and Figure 3-45 • Write Access After Read onto Same Address are new.	3-71 to 3-73
	Figure 3-53 • Timing Diagram was updated.	3-80
	Notes were added to the package diagrams identifying if they were top or bottom view.	N/A
	The A3PE1500 "208-Pin PQFP" table is new.	4-4
	The A3PE1500 "484-Pin FBGA" table is new.	4-18
	The A3PE1500 "A3PE1500 Function" table is new.	4-24
Advance v0.6 (January 2007)	In the "Packaging Tables" table, the number of I/Os for the A3PE1500 was changed for the FG484 and FG676 packages.	ii
Advance v0.5 (April 2006)	B-LVDS and M-LDVS are new I/O standards added to the datasheet.	N/A
	The term flow-through was changed to pass-through.	N/A
	Figure 2-8 • Very-Long-Line Resources was updated.	2-8
	The footnotes in Figure 2-27 • CCC/PLL Macro were updated.	2-28
	The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.	2-24
	The "SRAM and FIFO" section was updated.	2-21
	The "RESET" section was updated.	2-25
	The "WCLK and RCLK" section was updated.	2-25
	The "RESET" section was updated.	2-25
	The "RESET" section was updated.	2-27
	B-LVDS and M-LDVS are new I/O standards added to the datasheet.	N/A
	The term flow-through was changed to pass-through.	N/A
	Figure 2-8 • Very-Long-Line Resources was updated.	2-8
	The footnotes in Figure 2-27 • CCC/PLL Macro were updated.	2-28
	The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.	2-24
	The "SRAM and FIFO" section was updated.	2-21
	The "RESET" section was updated.	2-25
	The "WCLK and RCLK" section was updated.	2-25

Datasheet Categories

Categories

In order to provide the latest information to designers, some datasheet parameters are published before data has been fully characterized from silicon devices. The data provided for a given device, as highlighted in the "[ProASIC3E Device Status](#)" table on page II, is designated as either "Product Brief," "Advance," "Preliminary," or "Production." The definitions of these categories are as follows:

Product Brief

The product brief is a summarized version of a datasheet (advance or production) and contains general product information. This document gives an overview of specific device and family information.

Advance

This version contains initial estimated information based on simulation, other products, devices, or speed grades. This information can be used as estimates, but not for production. This label only applies to the DC and Switching Characteristics chapter of the datasheet and will only be used when the data has not been fully characterized.

Preliminary

The datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.

Production

This version contains information that is considered to be final.

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